

# INCHANGE SEMICONDUCTOR

# isc N-Channel MOSFET Transistor

# IPA65R650CE

### FEATURES

- With TO-220F packaging
- High speed switching
- · Very high commutation ruggedness
- · Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operationz

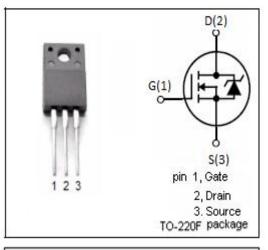
### APPLICATIONS

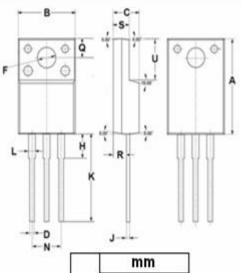
- · PFC stages, hard switching PWM stages and resonant switching
- PC Silverbox, Adapter, LCD & PDP TV
- · Lighting, Server, Telecom and UPS

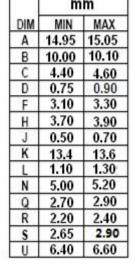
#### • ABSOLUTE MAXIMUM RATINGS(Ta=25℃) VALUE SYMBOL UNIT PARAMETER **Drain-Source Voltage** 650 V VDSS $V_{\text{GSS}}$ Gate-Source Voltage $\pm 20$ V Drain Current-Continuous@Tc=25°C 10.1 Ь А Tc=100℃ 6.4 Drain Current-Single Pulsed 18 **I**DM А $\mathbf{P}_{\mathsf{D}}$ **Total Dissipation** 28 W Tį **Operating Junction Temperature** -40~150 °C -40~150 °C Storage Temperature Tstg

### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	4.5	°C/W	
Rth(ch-a)	n(ch-a) Channel-to-ambient thermal resistance		°C/W	







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### **ELECTRICAL CHARACTERISTICS**

#### $T_{C}\text{=}25^{\circ}\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 1mA	650			V
V <sub>GS</sub> (th)	Gate Threshold Voltage	V <sub>DS</sub> =±20V; I <sub>D</sub> =0.21mA	2.5		3.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =2.1A		540	650	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> = 0V			±0.1	μA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = 650V; V <sub>GS</sub> = 0V			1	μA
V <sub>SDF</sub>	Diode forward voltage	I <sub>SD</sub> =3.2A, V <sub>GS</sub> = 0 V		0.9		v

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